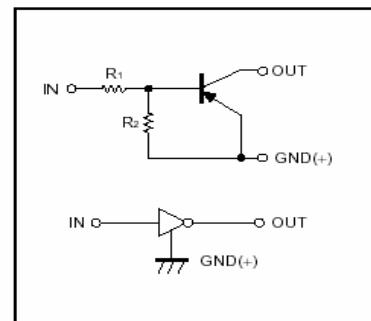


Features

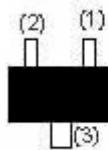
- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTA143EE

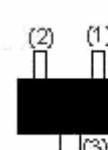


1.IN
2.GND
3.OUT

SOT-523

Addreviated symbol: 13

DTA143EUA

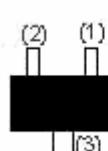


1.IN
2.GND
3.OUT

SOT-323

Addreviated symbol: 13

DTA143EKA

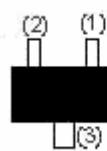


1.IN
2.GND
3.OUT

SOT-23-3L

Addreviated symbol: 13

DTA143ECA



1.IN
2.GND
3.OUT

SOT-23

Addreviated symbol: 13

DTA143ESA



1.GND
2.OUT
3.IN

TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA143E□)					Unit			
		E	UA	KA	CA	SA				
Supply voltage	V _{CC}	-50					V			
Input voltage	V _{IN}	-30~10					V			
Output current	I _O	-100					mA			
	I _{C(MAX)}	-100								
Power dissipation	P _d	150	200			300	mW			
Junction temperature	T _j	150					°C			
Storage temperature	T _{stg}	-55~150					°C			

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.5	V	V _{CC} =-5V , I _O =-100μA
	V _{I(on)}	-3				V _O =-0.3V , I _O =-20 mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-10mA/-0.5mA
Input current	I _I			-1.8	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V , I _I =0
DC current gain	G _I	30				V _O =-5V , I _O =-10mA
Input resistance	R _I	3.29	4.7	6.11	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =-10V , I _O =5mA,f=100MHz

Typical Characteristics
